## NSN 5962-01-449-1568

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View Online at https://aerobasegroup.com/nsn/5962-01-449-1568

Body Length:
1.485 inches
Body Width:
Between 0.240 inches and 0.310 inches
Body Height:
Between 0.030 inches and 0.215 inches
Maximum Power Dissipation Rating:
1.5 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15i
Features Provided:
Electrostatic sensitive and ultraviolet erasable and low bias and 3-state output and programmed and w/clock
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
24 input
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
D-15 mil-m-38510
Current Rating Per Characteristic:
225.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, cmos, uv erasable, programmable logic device, programmed
Voltage Rating And Type Per Characteristic:

-2.0 volts power source and 7.0 volts power source

### **Capitance Rating Per Characteristic:**

10.00 input picofarads and 12.00 output picofarads

### **Memory Device Type:**

Pal

#### **Special Features:**

Altered item make from 5962-901102xa, firmware/ version discription document vdd0355-01.00

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Test	Data	Docu	ıment
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

28 printed circuit

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Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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